

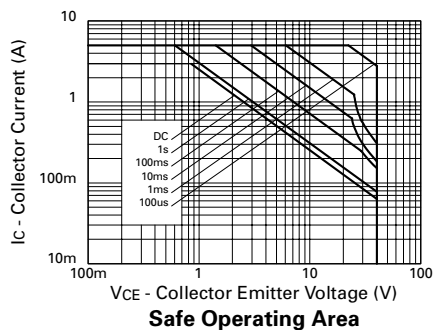
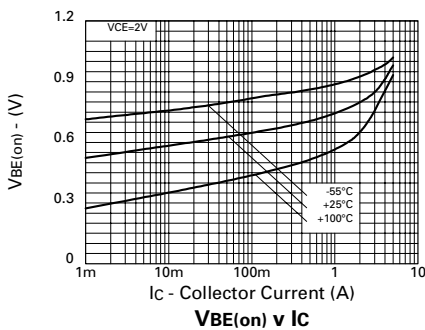
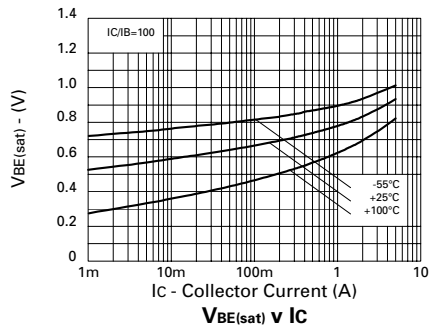
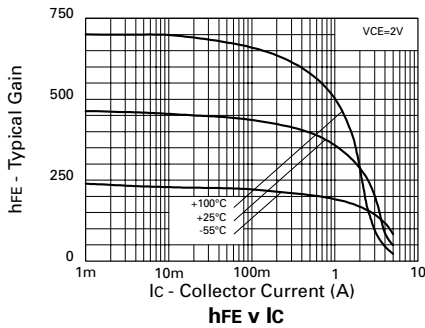
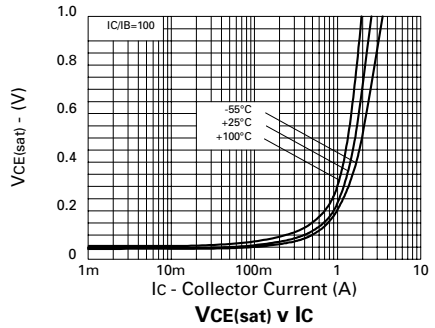
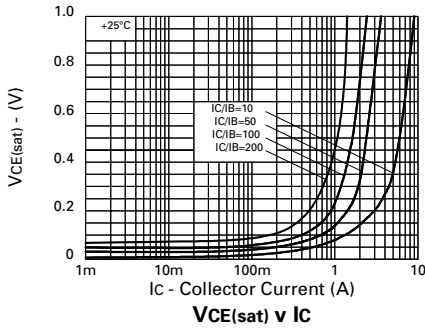
FZT1151A

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}\text{C}$).

PARAMETER	SYMBOL	VALUE			UNIT	CONDITIONS.
		MIN.	TYP.	MAX.		
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-45	-95		V	$I_C = -100\mu\text{A}$
Collector-Emitter Breakdown Voltage	V_{CES}	-40	-90		V	$I_C = -100\mu\text{A}$
Collector-Emitter Breakdown Voltage	V_{CEO}	-40	-85		V	$I_C = -10\text{mA}^*$
Collector-Emitter Breakdown Voltage	V_{CEV}	-40	-90		V	$I_C = -100\mu\text{A}$, $V_{EB} = +1\text{V}$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5	-8.5		V	$I_E = -100\mu\text{A}$
Collector Cut-Off Current	I_{CBO}		-0.3	-100	nA	$V_{CB} = -36\text{V}$
Emitter Cut-Off Current	I_{EBO}		-0.3	-100	nA	$V_{EB} = -4\text{V}$
Collector Emitter Cut-Off Current	I_{CES}		-0.3	-100	nA	$V_{CE} = -32\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$		-60 -120 -140 -170 -200	-90 -180 -220 -260 -300	mV mV mV mV mV	$I_C = -0.1\text{A}$, $I_B = -1.0\text{mA}^*$ $I_C = -0.5\text{A}$, $I_B = -5\text{mA}^*$ $I_C = -1\text{A}$, $I_B = -20\text{mA}^*$ $I_C = -1.8\text{A}$, $I_B = -70\text{mA}^*$ $I_C = -3\text{A}$, $I_B = -250\text{mA}^*$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$		-985	-1100	mV	$I_C = -3\text{A}$, $I_B = -250\text{mA}^*$
Base-Emitter Turn-On Voltage	$V_{BE(on)}$		-850	-1000	mV	$I_C = -3\text{A}$, $V_{CE} = -2\text{V}^*$
Static Forward Current Transfer Ratio	h_{FE}	270 250 180 100	450 400 300 190 45	800		$I_C = -10\text{mA}$, $V_{CE} = -2\text{V}^*$ $I_C = -0.5\text{A}$, $V_{CE} = -2\text{V}^*$ $I_C = -2\text{A}$, $V_{CE} = -2\text{V}^*$ $I_C = -3\text{A}$, $V_{CE} = -2\text{V}^*$ $I_C = -5\text{A}$, $V_{CE} = -2\text{V}^*$
Transition Frequency	f_T		145		MHz	$I_C = -50\text{mA}$, $V_{CE} = -10\text{V}$ $f = 50\text{MHz}$
Output Capacitance	C_{cb}		40		pF	$V_{CB} = -10\text{V}$, $f = 1\text{MHz}$
Switching Times	t_{on}		170		ns	$I_C = -2\text{A}$, $I_B = -20\text{mA}$, $V_{CC} = -30\text{V}$
	t_{off}		460		ns	$I_C = -2\text{A}$, $I_B = \pm 20\text{mA}$, $V_{CC} = -30\text{V}$

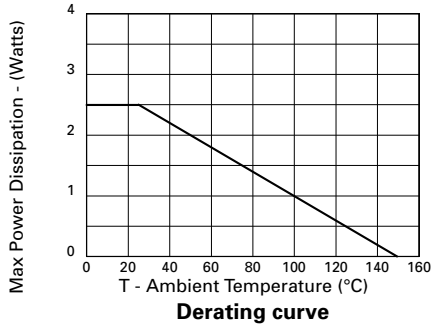
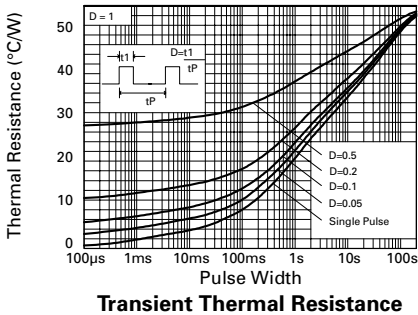
*Measured under pulsed conditions. Pulse width=300 μs . Duty cycle $\leq 2\%$.

TYPICAL CHARACTERISTICS



FZT1151A

THERMAL CHARACTERISTICS



SPICE PARAMETERS

*ZETEX FZT1151A Spice model Last revision 12/12/96

*

```
.MODEL FZT1151A PNP IS =1.7e-12 NF =1.004 ISE=1.02e-13
+ NE =1.55 BF =562 VAF=26.01 IKF=3.5 NR =.97
+ ISC= 1.5e-13 NC =1.3 BR =38 VAR=2.41 IKR=0.3
+ RE =25.37e-3 RB =250e-3 RC =25e-3 CJE=440e-12
+ CJC=160e-12 VJC=1.058 MJC= 0.5678 TF =0.8e-9 TR =55.5e-9
```

*

© 1995 ZETEX PLC

The copyright in this model and the design embodied belong to Zetex PLC ("Zetex"). It is supplied free of charge by Zetex for the purpose of research and design and may be used or copied intact (including this notice) for that purpose only. All other rights are reserved. The model is believed accurate but no condition or warranty as to its merchantability or fitness for purpose is given and no liability in respect of any use is accepted by Zetex PLC, its distributors or agents.